Product data sheet

# 1. General description

General-purpose Zener diodes in an SOD123F small and flat lead Surface-Mounted Device (SMD) plastic package.

## 2. Features and benefits

- Total power dissipation: ≤ 830 mW
- Three tolerance series: ±1 %, ±2 % and approximately ±5 %
- Wide working voltage range: nominal 2.4 V to 75 V (E24 range)
- Small plastic package suitable for surface-mounted design
- Qualified according to AEC-Q101 and recommended for use in automotive applications

## 3. Applications

· General regulation functions

## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{F}$	forward voltage	I <sub>F</sub> = 10 mA	[1]	-	-	0.9	V
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[2]	-	-	375	mW
			[3]	-	-	830	mW

- [1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.



# 5. Pinning information

#### **Table 2. Pinning**

Pin	Symbol	Description		Simplified outline	Graphic symbol
1	K	cathode	[1]	1 2	и <b>П</b> а
2	Α	anode			^ <u> </u>
					006aaa152

[1] The marking bar indicates the cathode.

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package		
	Name	Description	Version
BZT52H-Q series[1]	-	plastic surface-mounted package; 2 leads	SOD123F

[1] The series consists of 111 types with 37 breakdown voltages with nominal working voltages from 2.4 V to 75 V and ±1 %, ±2 % and ±5 % tolerances.

# 7. Marking

Table 4. Marking codes

Type number	Marking code	Type number	Marking code	Type number	Marking code
BZT52H-A2V4-Q	FT	BZT52H-B2V4-Q	DC	BZT52H-C2V4-Q	В3
BZT52H-A2V7-Q	FU	BZT52H-B2V7-Q	DD	BZT52H-C2V7-Q	B4
BZT52H-A3V0-Q	FV	BZT52H-B3V0-Q	DE	BZT52H-C3V0-Q	B5
BZT52H-A3V3-Q	FW	BZT52H-B3V3-Q	DF	BZT52H-C3V3-Q	B6
BZT52H-A3V6-Q	FX	BZT52H-B3V6-Q	DG	BZT52H-C3V6-Q	B7
BZT52H-A3V9-Q	FY	BZT52H-B3V9-Q	DH	BZT52H-C3V9-Q	B8
BZT52H-A4V3-Q	FZ	BZT52H-B4V3-Q	DJ	BZT52H-C4V3-Q	B9
BZT52H-A4V7-Q	G1	BZT52H-B4V7-Q	DK	BZT52H-C4V7-Q	ВА
BZT52H-A5V1-Q	G2	BZT52H-B5V1-Q	DL	BZT52H-C5V1-Q	ВВ
BZT52H-A5V6-Q	G3	BZT52H-B5V6-Q	DM	BZT52H-C5V6-Q	ВС
BZT52H-A6V2-Q	G4	BZT52H-B6V2-Q	DN	BZT52H-C6V2-Q	BD
BZT52H-A6V8-Q	G5	BZT52H-B6V8-Q	DP	BZT52H-C6V8-Q	BE
BZT52H-A7V5-Q	G6	BZT52H-B7V5-Q	DQ	BZT52H-C7V5-Q	BF
BZT52H-A8V2-Q	G7	BZT52H-B8V2-Q	DR	BZT52H-C8V2-Q	BG
BZT52H-A9V1-Q	G8	BZT52H-B9V1-Q	DS	BZT52H-C9V1-Q	ВН
BZT52H-A10-Q	G9	BZT52H-B10-Q	DT	BZT52H-C10-Q	BJ
BZT52H-A11-Q	GA	BZT52H-B11-Q	DU	BZT52H-C11-Q	BK
BZT52H-A12-Q	GB	BZT52H-B12-Q	DV	BZT52H-C12-Q	BL
BZT52H-A13-Q	GC	BZT52H-B13-Q	DW	BZT52H-C13-Q	ВМ
BZT52H-A15-Q	GD	BZT52H-B15-Q	DX	BZT52H-C15-Q	BN
BZT52H-A16-Q	GE	BZT52H-B16-Q	DY	BZT52H-C16-Q	ВР
BZT52H-A18-Q	GF	BZT52H-B18-Q	DZ	BZT52H-C18-Q	BQ
BZT52H-A20-Q	GG	BZT52H-B20-Q	E1	BZT52H-C20-Q	BR
BZT52H-A22-Q	GH	BZT52H-B22-Q	E2	BZT52H-C22-Q	BS
BZT52H-A24-Q	GJ	BZT52H-B24-Q	E3	BZT52H-C24-Q	ВТ
BZT52H-A27-Q	GK	BZT52H-B27-Q	E4	BZT52H-C27-Q	BU
BZT52H-A30-Q	GL	BZT52H-B30-Q	E5	BZT52H-C30-Q	BV
BZT52H-A33-Q	GM	BZT52H-B33-Q	E6	BZT52H-C33-Q	BW
BZT52H-A36-Q	GN	BZT52H-B36-Q	E7	BZT52H-C36-Q	BX
BZT52H-A39-Q	GP	BZT52H-B39-Q	E8	BZT52H-C39-Q	BY
BZT52H-A43-Q	GY	BZT52H-B43-Q	E9	BZT52H-C43-Q	BZ
BZT52H-A47-Q	GR	BZT52H-B47-Q	EA	BZT52H-C47-Q	C1
BZT52H-A51-Q	GS	BZT52H-B51-Q	EB	BZT52H-C51-Q	C2
BZT52H-A56-Q	GT	BZT52H-B56-Q	EC	BZT52H-C56-Q	C3
BZT52H-A62-Q	GU	BZT52H-B62-Q	ED	BZT52H-C62-Q	C4
BZT52H-A68-Q	GV	BZT52H-B68-Q	EE	BZT52H-C68-Q	C5
BZT52H-A75-Q	GW	BZT52H-B75-Q	EF	BZT52H-C75-Q	C6

## 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
I <sub>F</sub>	forward current			-	250	mA
I <sub>ZSM</sub>	non-repetitive peak reverse current		[1]	-	see Tables 8, 9 and 10	
P <sub>ZSM</sub>	non-repetitive peak reverse power dissipation		[1]	-	40	W
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[2]	-	375	mW
			[3]	-	830	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	+150	°C
T <sub>stg</sub>	storage temperature			-65	+150	°C

- [1]  $t_p = 100 \mu s$ ; square wave;  $T_j = 25 \,^{\circ} C$  prior to surge. [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from	in free air	[1]	-	-	330	K/W
	junction to ambient		[2]	-	-	150	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		[3]	-	-	70	K/W

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.
- Soldering point of cathode tab.

## 10. Characteristics

## **Table 7. Characteristics**

 $T_i$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 10 mA	[1]	-	-	0.9	V

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .

Table 8. Characteristics per type; BZT52H-A2V4-Q to BZT52H-C24-Q

 $T_i$  = 25 °C unless otherwise specified.

-xxx vo V <sub>z</sub> I <sub>z</sub> :		voltag V <sub>Z</sub> (V)	voltage resis $V_Z(V)$ $r_{dif}(S)$		differential	Rever currer I <sub>R</sub> (µA	nt	Temp coeffi S <sub>Z</sub> (m I <sub>Z</sub> = 5	V/K)	Diode capacitance C <sub>d</sub> (pF) [1]	Non-repetitive peak reverse current I <sub>ZSM</sub> (A) [2]
		Min	Max	I <sub>Z</sub> = 1 mA	I <sub>Z</sub> = 5 mA	Max	V <sub>R</sub> (V)	Min	Max	Max	Max
2V4-Q	Α	2.37	2.43	400	85	50	1	-3.5	0.0	450	6.0
	В	2.35	2.45								
	С	2.20	2.60								
2V7-Q	Α	2.67	2.73	500	83	20	1	-3.5	0.0	450	6.0
	В	2.65	2.75								
	С	2.50	2.90								
3V0-Q	Α	2.97	3.03	500	95	10	1	-3.5	0.0	450	6.0
	В	2.94	3.06								
	С	2.80	3.20								
3V3-Q	Α	3.26	3.34	500	95	5	1	-3.5	0.0	450	6.0
	В	3.23	3.37								
	С	3.10	3.50								
3V6-Q	Α	3.56	3.64	500	95	5	1	-3.5	0.0	450	6.0
	В	3.53	3.67								
	С	3.40	3.80								
3V9-Q	Α	3.86	3.94	500	95	3	1	-3.5	0.0	450	6.0
	В	3.82	3.98								
	С	3.70	4.10								
4V3-Q	Α	4.25	4.35	500	95	3	1	-3.5	0.0	450	6.0
	В	4.21	4.39								
	С	4.00	4.60								
4V7-Q	Α	4.65	4.75	500	78	3	2	-3.5	0.2	300	6.0
	В	4.61	4.79								
	С	4.40	5.00								
5V1-Q	Α	5.04	5.16	480	60	2	2	-2.7	1.2	300	6.0
	В	5.00	5.20								
	С	4.80	5.40								
5V6-Q	Α	5.54	5.66	400	40	1	2	-2.0	2.5	300	6.0
	В	5.49	5.71								
	С	5.20	6.00								
6V2-Q	Α	6.13	6.27	150	10	3	4	0.4	3.7	200	6.0
	В	6.08	6.32								
	С	5.80	6.60								
6V8-Q	Α	6.73	6.87	80	8	2	4	1.2	4.5	200	6.0
	В	6.66	6.94								
	С	6.40	7.20								
7V5-Q	Α	7.42	7.58	80	10	1	5	2.5	5.3	150	4.0
	В	7.35	7.65								
	С	7.00	7.90	1							

BZT52H Sel -xxx		Working voltage V <sub>Z</sub> (V) I <sub>Z</sub> = 5 mA		$\begin{array}{l} \text{Maximum differential} \\ \text{resistance} \\ \text{r}_{\text{dif}}\left(\Omega\right) \end{array}$		Rever currer I <sub>R</sub> (µA	nt	Temp coeffi S <sub>Z</sub> (m I <sub>Z</sub> = 5	V/K)	Diode capacitance C <sub>d</sub> (pF) [1]	Non-repetitive peak reverse current I <sub>ZSM</sub> (A) [2]
		Min	Max	I <sub>Z</sub> = 1 mA	I <sub>Z</sub> = 5 mA	Max	V <sub>R</sub> (V)	Min	Max	Max	Max
8V2-Q	Α	8.11	8.29	80	10	0.7	5	3.2	6.2	150	4.0
	В	8.04	8.36								
	С	7.70	8.70	1							
9V1-Q	Α	9.00	9.20	100	10	0.5	6	3.8	7.0	150	3.0
	В	8.92	9.28	]							
	С	8.50	9.60	1							
10-Q	Α	9.90	10.10	70	10	0.2	7	4.5	8.0	90	3.0
	В	9.80	10.20	1							
	С	9.40	10.60	1							
11-Q	Α	10.89	11.11	70	10	0.1	8	5.4	9.0	85	2.5
	В	10.80	11.20	1							
	С	10.40	11.60	1							
12-Q	Α	11.88	12.12	90	10	0.1	8	6.0	10.0	85	2.5
	В	11.80	12.20	1							
	С	11.40	12.70	1							
13-Q	Α	12.87	13.13	110	10	0.1	8	7.0	11.0	80	2.5
	В	12.70	13.30	1							
	С	12.40	14.10	1							
15-Q	Α	14.85	15.15	110	15	0.05	10.5	9.2	13.0	75	2.0
	В	14.70	15.30	]							
	С	13.80	15.60	1							
16-Q	Α	15.84	16.16	170	20	0.05	11.2	10.4	14.0	75	1.5
	В	15.70	16.30	]							
	С	15.30	17.10	1							
18-Q	Α	17.82	18.18	170	20	0.05	12.6	12.4	16.0	70	1.5
	В	17.60	18.40								
	С	16.80	19.10								
20-Q	Α	19.80	20.20	220	20	0.05	14	14.4	18.0	60	1.5
	В	19.60	20.40								
	С	18.80	21.20								
22-Q	Α	21.78	22.22	220	25	0.05	15.4	16.4	20.0	60	1.25
	В	21.60	22.40	]							
	С	20.80	23.30	]							
24-Q	Α	23.76	24.24	220	30	0.05	16.8	18.4	22.0	55	1.25
	В	23.50	24.50	1		0.50		22.0			
	С	22.80	25.60	1							

<sup>[1]</sup> f = 1 MHz;  $V_R = 0 \text{ V}$ [2]  $t_p = 100 \text{ } \mu\text{s}$ ;  $T_{amb} = 25 \text{ }^{\circ}\text{C}$ 

Table 9. Characteristics per type; BZT52H-A27-Q to BZT52H-C51-Q

 $T_i$  = 25 °C unless otherwise specified.

BZT52H -xxx	Sel	Working voltag V <sub>Z</sub> (V) I <sub>Z</sub> = 2 I	e	$\begin{array}{l} \text{Maximum differential} \\ \text{resistance} \\ \text{r}_{\text{dif}}\left(\Omega\right) \end{array}$		curren	Reverse current I <sub>R</sub> (μA)		erature cient V/K) mA	Diode capacitance C <sub>d</sub> (pF) [1]	Non-repetitive peak reverse current I <sub>ZSM</sub> (A) [2]
		Min	Max	I <sub>Z</sub> = 1 mA	I <sub>Z</sub> = 5 mA	Max	V <sub>R</sub> (V)	Min	Max	Max	Max
27-Q	Α	26.73	27.27	250	40	0.05	18.9	21.4	25.3	50	1.0
	В	26.50	27.50								
	С	25.10	28.90								
30-Q	А	29.70	30.30	250	40	0.05	21	24.4	29.4	50	1.0
	В	29.40	30.60								
	С	28.00	32.00								
33-Q	А	32.67	33.33	250	40	0.05	23.1	27.4	33.4	45	0.9
	В	32.30	33.70								
	С	31.00	35.00								
36-Q	Α	35.64	36.36	250	60	0.05	25.2	30.4	37.4	45	0.8
	В	35.30	36.70								
	С	34.00	38.00								
39-Q	Α	38.61	39.39	300	75	0.05	27.3	33.4	41.2	45	0.7
	В	38.20	39.80								
	С	37.00	41.00								
43-Q	Α	42.57	43.43	325	80	0.05	30.1	37.6	46.6	40	0.6
	В	42.10	43.90								
	С	40.00	46.00								
47-Q	Α	46.53	47.47	325	90	0.05	32.9	42.0	51.8	40	0.5
	В	46.10	47.90	1							
	С	44.00	50.00								
51-Q	Α	50.49	51.51	350	100	0.05	35.7	46.6	57.2	40	0.4
	В	50.00	52.00	1							
	С	48.00	54.00								

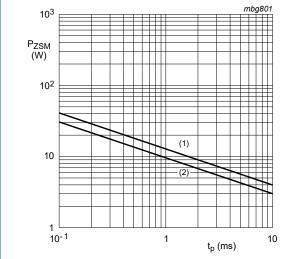
<sup>[1]</sup>  $f = 1 \text{ MHz}; V_R = 0 \text{ V}$ [2]  $t_p = 100 \text{ } \mu\text{s}; T_{amb} = 25 \text{ }^{\circ}\text{C}.$ 

Table 10. Characteristics per type; BZT52H-A56-Q to BZT52H-C75-Q

 $T_i$  = 25 °C unless otherwise specified.

BZT52H Sel -xxx		Sel Workin voltage V <sub>Z</sub> (V) I <sub>Z</sub> = 2 n		$\begin{array}{l} \text{Maximum differential} \\ \text{resistance} \\ \text{r}_{\text{dif}}\left(\Omega\right) \end{array}$		curren	Reverse current I <sub>R</sub> (µA)		erature cient V/K) mA	Diode capacitance C <sub>d</sub> (pF) [1]	Non-repetitive peak reverse current I <sub>ZSM</sub> (A) [2]
		Min	Max	I <sub>Z</sub> = 0.5 mA	I <sub>Z</sub> = 2 mA	Max	V <sub>R</sub> (V)	Min	Max	Max	Max
56-Q	Α	55.44	56.56	375	120	0.05	39.2	52.2	63.8	40	0.3
	В	54.90	57.10								
	С	52.00	60.00	-							
62-Q	Α	61.38	62.62	400	140	0.05	43.4	58.8	71.6	35	0.3
	В	60.80	63.20	-							
	С	58.00	66.00								
68-Q	Α	67.32	68.68	400	160	0.05	47.6	65.6	79.8	35	0.25
	В	66.60	69.40	1							
	С	64.00	72.00	1							
75-Q	Α	74.25	75.75	400	175	0.05	52.5	73.4	88.6	35	0.20
	В	73.50	76.50	1							
	С	70.00	79.00	1							

- [1]  $f = 1 \text{ MHz}; V_R = 0 \text{ V}$
- [2]  $t_p = 100 \mu s$ ;  $T_{amb} = 25 °C$ .



(1) T<sub>i</sub> = 25 °C (before surge)

(2)  $T_j$  = 150 °C (before surge)

Fig. 1. Non-repetitive peak reverse power dissipation as a function of pulse duration; maximum values

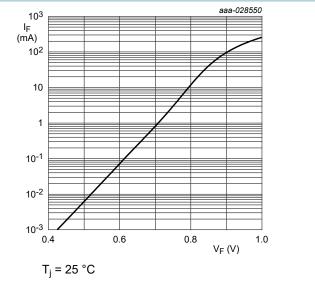


Fig. 2. Forward current as a function of forward voltage; typical values (BZT52H-A/B/C2V4-Q)

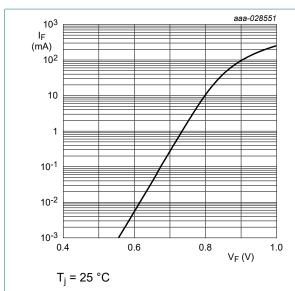


Fig. 3. Forward current as a function of forward voltage; typical values (BZT52H-A/B/C6V8-Q)

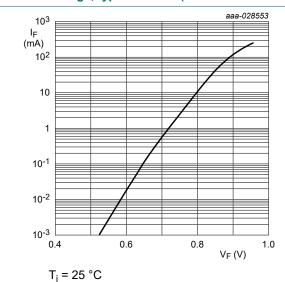


Fig. 5. Forward current as a function of forward voltage; typical values (BZT52H-A/B/C75-Q)

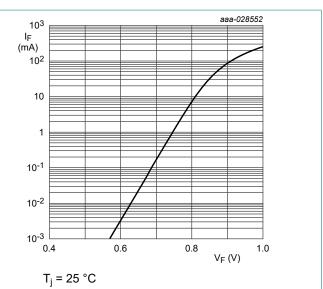


Fig. 4. Forward current as a function of forward voltage; typical values (BZT52H-A/B/C7V5-Q)

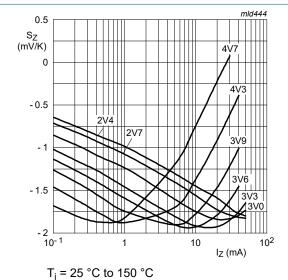
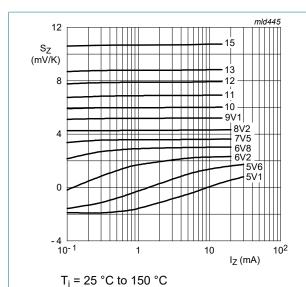
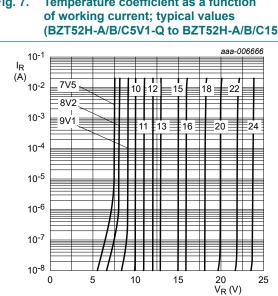


Fig. 6. Temperature coefficient as a function of working current; typical values (BZT52H-A/B/C2V4-Q to BZT52H-A/B/C4V7-Q)



Temperature coefficient as a function Fig. 7. of working current; typical values (BZT52H-A/B/C5V1-Q to BZT52H-A/B/C15-Q)



Reverse current as a function of Fig. 9. reverse voltage; typical values (BZT52H-A/B/C7V5-Q to BZT52H-A/B/C24-Q)

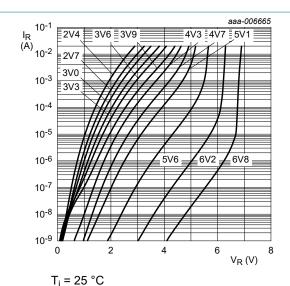


Fig. 8. Reverse current as a function of reverse voltage; typical values (BZT52H-A/B/C2V4-Q to BZT52H-A/B/C6V8-Q)

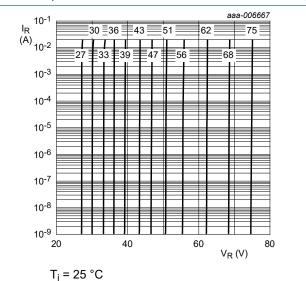


Fig. 10. Reverse current as a function of reverse voltage; typical values (BZT52H-A/B/C27-Q to BZT52H-A/B/C75-Q)

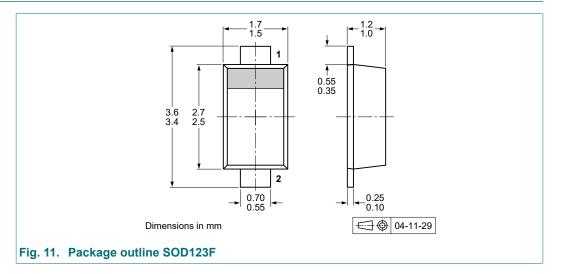
## 11. Test information

 $T_i = 25 \,^{\circ}C$ 

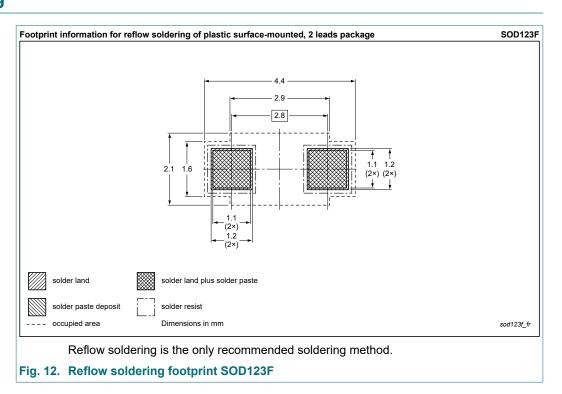
#### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

# 12. Package outline



## 13. Soldering



# 14. Revision history

## **Table 11. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BZT52H-Q_SER v.1	20211004	Product data sheet	-	-

## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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